

## Single Line ESD Protection Diode Array

**UM5075 SOD523**

**UM5079 DFN2 1.0×0.6**

### General Description

The UM5075/5079 ESD protection diode is designed to replace multilayer varistors (MLVs) in portable applications such as cell phones, notebook computers, and PDA's. They feature large cross-sectional area junctions for conducting high transient currents, offer desirable electrical characteristics for board level protection, such as fast response time, lower operating voltage, lower clamping voltage and no device degradation when compared to MLVs.

The UM5075/5079 ESD protection diode protects sensitive semiconductor components from damage or upset due to electrostatic discharge (ESD) and other voltage induced transient events. The UM5075 is available in SOD523 package and the UM5079 is available in DFN2 1.0×0.6 (compatible with SOD882/SOD923) package, both with working voltage of 7 volt.

It gives designer the flexibility to protect one unidirectional line in applications where arrays are not practical. Additionally, it may be "sprinkled" around the board in applications where board space is at a premium. It may be used to meet the ESD immunity requirements of IEC 61000-4-2, ±15kV air, ±15kV contact discharge.

### Applications

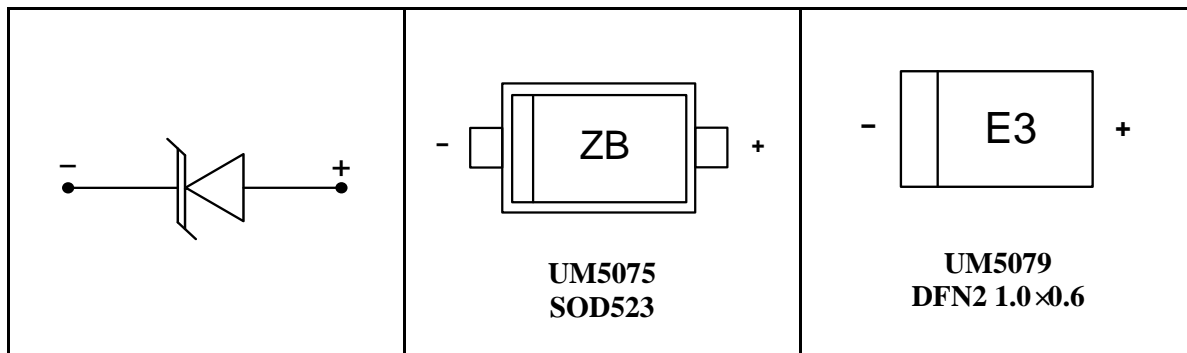
- Cell Phone Handsets and Accessories
- Personal Digital Assistants (PDA's)
- Notebooks, Desktops and Servers
- Portable Instrumentation
- Cordless Phones
- Digital Cameras
- Peripherals
- MP3 Players

### Features

- Transient Protection for Data Lines to IEC 61000-4-2 (ESD) ±15kV (Air), ±15kV (Contact)
- IEC 61000-4-4 (EFT) 50A (t<sub>p</sub>=5/50ns)
- Small Package for Use in Portable Electronics
- Suitable Replacement for MLV's in ESD Protection Applications
- Protect One I/O or Power Line
- Low Clamping Voltage
- Stand-Off Voltage: 7V
- Low Leakage Current
- Solid-State Silicon-Avalanche Technology

### Pin Configurations

### Top View



## Ordering Information

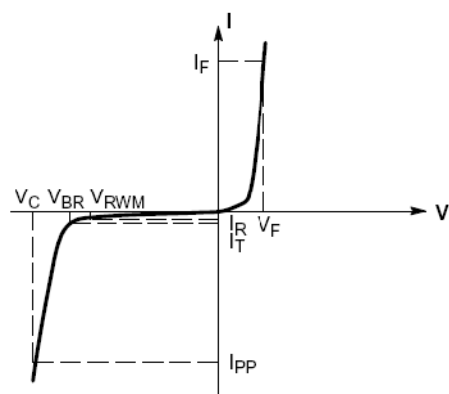
Part Number	Working Voltage	Packaging Type	Channel	Marking Code	Shipping Qty
UM5075	7.0V	SOD523	1	ZB	3000pcs/7 Inch Tape & Reel
UM5079		DFN2 1.0×0.6		E3	5000pcs/7 Inch Tape & Reel

## Absolute Maximum Ratings

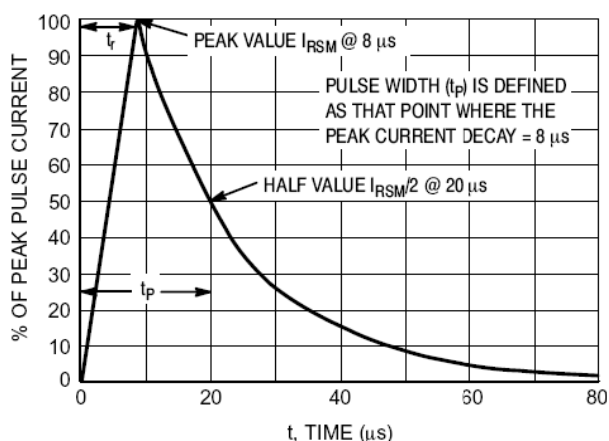
Rating	Symbol	Value	Unit
Peak Pulse Power ( $t_p=8/20\mu s$ )	$P_{PK}$	200	Watts
Maximum Peak Pulse Current ( $t_p=8/20\mu s$ )	$I_{PP}$	12	Amps
Maximum Peak Pulse Current ( $t_p=5/50ns$ )	$I_{PP}$	50	Amps
ESD per IEC 61000-4-2 (Air)	$V_{ESD}$	$\pm 15$	kV
ESD per IEC 61000-4-2 (Contact)	$V_{ESD}$	$\pm 15$	kV
Lead Soldering Temperature	$T_L$	260 (10 sec.)	$^{\circ}C$
Operating Temperature	$T_J$	-55 to +125	$^{\circ}C$
Storage Temperature	$T_{STG}$	-55 to +150	$^{\circ}C$

## Symbol Definition

Parameter	Symbol
Maximum Reverse Peak Pulse Current	$I_{PP}$
Clamping Voltage @ $I_{pp}$	$V_C$
Working Peak Reverse Voltage	$V_{RWM}$
Maximum Reverse Leakage Current @ $V_{RWM}$	$I_R$
Breakdown Voltage @ $I_T$	$V_{BR}$
Test Current	$I_T$
Forward Current	$I_F$
Forward Voltage @ $I_F$	$V_F$
Peak Power Dissipation	$P_{PK}$
Max. Capacitance @ $V_R=0V$ , $f=1MHz$	$C$



Uni-Directional TVS



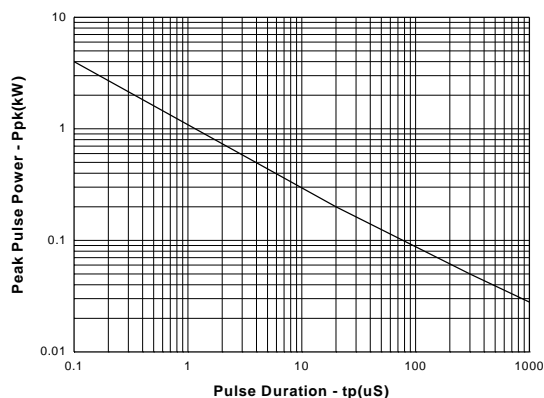
## Electrical Characteristics

(T=25 °C, Device for 7.0V Reverse Stand-Off Voltage)

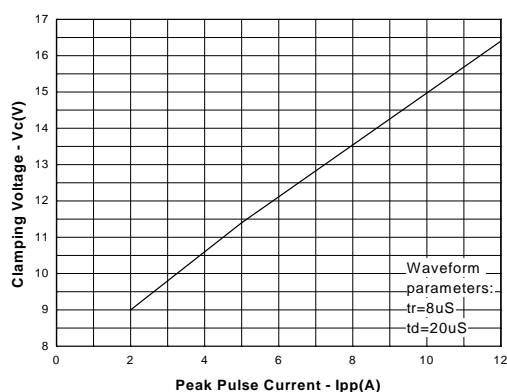
Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Reverse Stand-Off Voltage	$V_{RWM}$				7	V
Reverse Breakdown Voltage	$V_{BR}$	$I_T=1mA$	7.5	8.2	8.9	V
Reverse Leakage Current	$I_R$	$V_{RWM}=7V, T=25\text{ }^{\circ}C$		0.005	1	$\mu A$
Clamping Voltage	$V_C$	$I_{PP}=5A, t_p=8/20\mu s$			11.4	V
		$I_{PP}=12A, t_p=8/20\mu s$			16.4	
Forward Voltage	$V_F$	$I_F=10mA$		0.8		V
Junction Capacitance	$C_J$	$V_R=0V, f=1MHz$		40	50	pF
Junction Capacitance	$C_J$	$V_R=2.5V, f=1MHz$		30	40	pF

## Typical Operating Characteristics

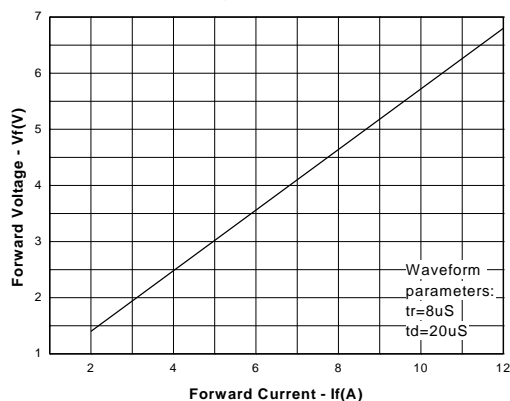
Non-Repetitive Peak Pulse Power vs. Pulse Time



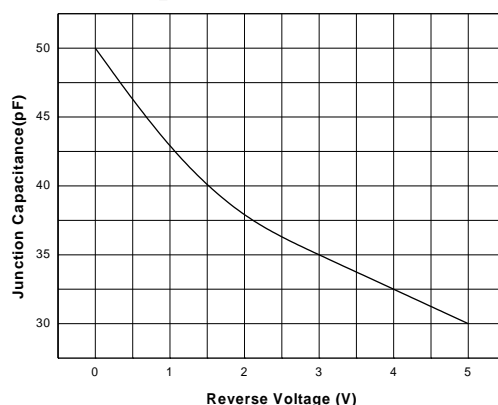
Clamping Voltage vs. Peak Pulse Current



Forward Voltage vs. Forward Current



Junction Capacitance vs. Reverse Voltage



---

**Applications Information****Device Connection Options**

UM5075/5079 ESD protection diode is designed to protect one data, I/O, or power supply line. The device is unidirectional and may be used on lines where the signal polarity is above ground. The cathode band should be placed towards the line that is to be protected.

**Circuit Board Layout Recommendations for Suppression of ESD**

Good circuit board layout is critical for the suppression of ESD induced transients. The following guidelines are recommended:

1. Place the TVS near the input terminals or connectors to restrict transient coupling.
2. Minimize the path length between the TVS and the protected line.
3. Minimize all conductive loops including power and ground loops.
4. The ESD transient return path to ground should be kept as short as possible.
5. Never run critical signals near board edges.
6. Use ground planes whenever possible. For multilayer printed-circuit boards, use ground vias.
7. Keep parallel signal paths to a minimum.
8. Avoid running protection conductors in parallel with unprotected conductor.
9. Minimize all printed-circuit board conductive loops including power and ground loops.
10. Avoid using shared transient return paths to a common ground point.

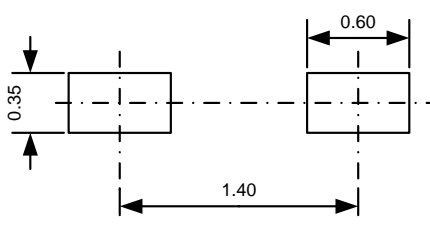
## Package Information

### UM5075 SOD523

#### Outline Drawing

DIMENSIONS						
Symbol	MILLIMETERS			INCHES		
	Min	Typ	Max	Min	Typ	Max
A	0.51	0.64	0.77	0.020	0.025	0.030
A1	0.50	0.60	0.70	0.020	0.024	0.028
b	0.25	0.30	0.35	0.010	0.012	0.014
c	0.08	-	0.15	0.003	-	0.006
D	0.70	0.80	0.90	0.028	0.031	0.035
E	1.10	1.20	1.30	0.043	0.047	0.051
E1	1.50	1.60	1.70	0.059	0.063	0.067
E2	0.20REF			0.008REF		
L	0.01	0.04	0.07	0.0004	0.002	0.003
$\theta$	7° REF			7° REF		

#### Land Pattern

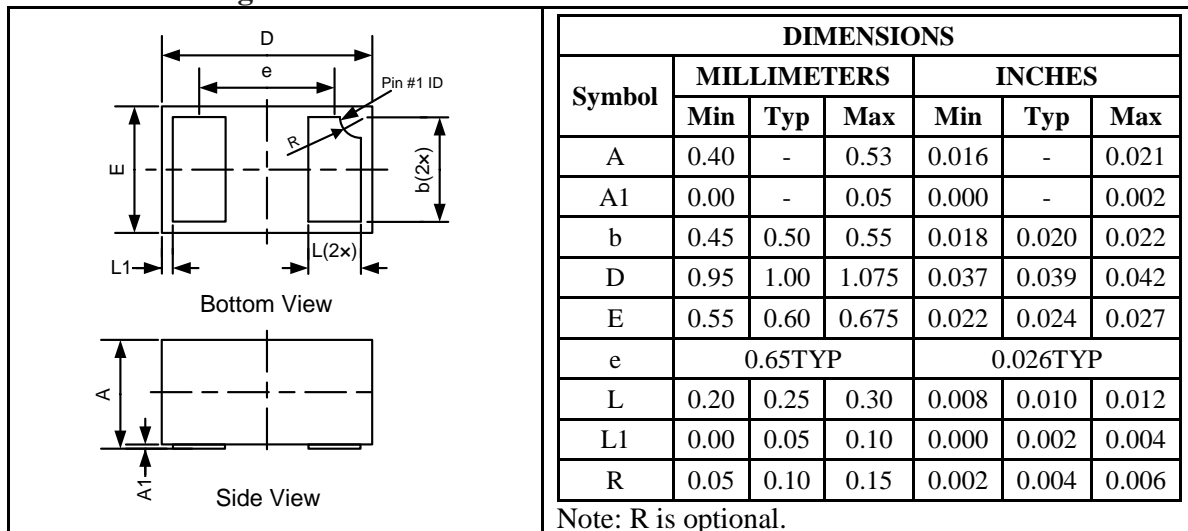
	<p>NOTES:</p> <ol style="list-style-type: none"> <li>Compound dimension: 1.20×0.80;</li> <li>Unit: mm;</li> <li>General tolerance <math>\pm 0.05\text{mm}</math> unless otherwise specified;</li> <li>The layout is just for reference.</li> </ol>
---	--

#### Tape and Reel Orientation

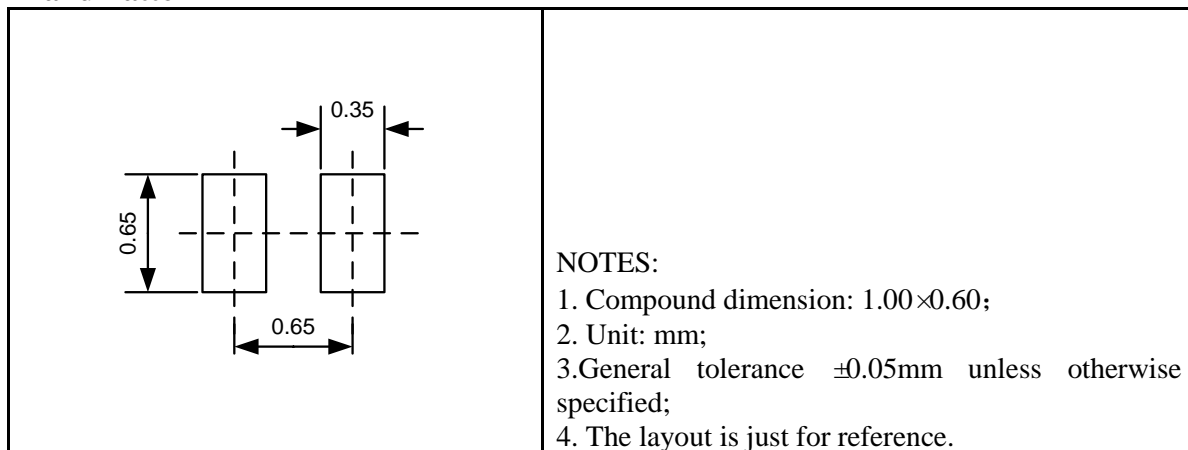


## UM5079 DFN2 1.0×0.6

### Outline Drawing



### Land Pattern



### Tape and Reel Specification



---

## **GREEN COMPLIANCE**

Union Semiconductor is committed to environmental excellence in all aspects of its operations including meeting or exceeding regulatory requirements with respect to the use of hazardous substances. Numerous successful programs have been implemented to reduce the use of hazardous substances and/or emissions.

All Union components are compliant with the RoHS directive, which helps to support customers in their compliance with environmental directives. For more green compliance information, please visit:

[http://www.union-ic.com/index.aspx?cat\\_code=RoHSDeclaration](http://www.union-ic.com/index.aspx?cat_code=RoHSDeclaration)

## **IMPORTANT NOTICE**

The information in this document has been carefully reviewed and is believed to be accurate. Nonetheless, this document is subject to change without notice. Union assumes no responsibility for any inaccuracies that may be contained in this document, and makes no commitment to update or to keep current the contained information, or to notify a person or organization of any update. Union reserves the right to make changes, at any time, in order to improve reliability, function or design and to attempt to supply the best product possible.